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Gunn diodes based on graded-gap semiconductor nitrides with boron nitride

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Effect of ge delta-doping of the Gan barrier on the performance of Ingan/Gan light-emitting diodes

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Efficiency enhancement of InGaN/GaN light-emitting diodes with pin-doped GaN quantum barrier

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Efficiency enhancement of ingan/gan leds with mg-si co-doped gan quantum barrier

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